

PHOTOCOUPLER PS9601,PS9601L

HIGH ISOLATION VOLTAGE, HIGH-SPEED 10 Mbps OPEN COLLECTOR OUTPUT TYPE 8-PIN DIP PHOTOCOUPLER -^

-NEPOC[™] Series-

DESCRIPTION

The PS9601 and PS9601L are optically coupled isolators containing a GaAlAs LED on the input side and a photo diode and a signal processing circuit on the output side on one chip.

The PS9601 is in a plastic DIP (Dual In-line Package) and the PS9601L is lead bending type (Gull-wing) for surface mounting.

FEATURES

- High isolation voltage (BV = 5 000 Vr.m.s.)
- High-speed response (tphL, tpLH = 50 ns TYP.)
- Low threshold input current (IFHL = 2.5 mA TYP.)
- · TTL, CMOS compatible with a resistor
- Ordering number of tape product: PS9601L-E3, E4: 1 000 pcs/reel
- ★ Safety standards
 - UL approved: File No. E72422 (S)
 - BSI approved: No. 8389, 8390

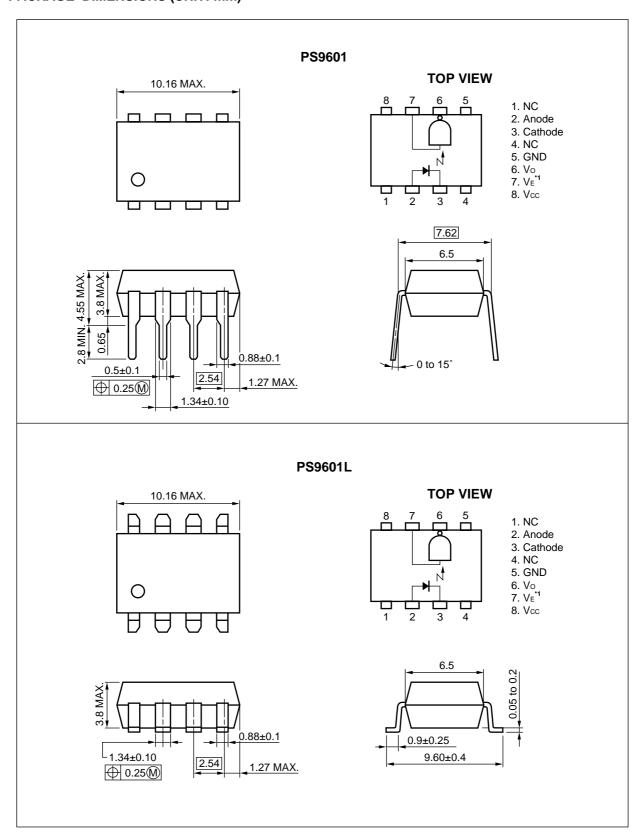
APPLICATIONS

- · Computer and peripheral manufactures
- · Electronic musical instruments
- Audio-visual
- Measurement equipment

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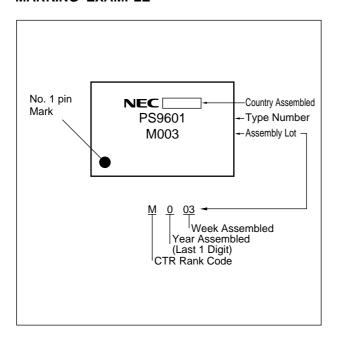
Not all devices/types available in every country. Please check with local NEC representative for availability and additional information.

★ PACKAGE DIMENSIONS (UNIT: mm)



*1 VE is pulled-up to

★ MARKING EXAMPLE



★ ORDERING INFORMATION

Part Number	Package	Packing Style	Application Part Number ^{*1}
PS9601	8-pin DIP	Magazine case 50 pcs	PS9601
PS9601L			PS9601L
PS9601L-E3		Embossed Tape 1 000 pcs/reel	
PS9601L-E4			

^{*1} For the application of the Safety Standard, following part number should be used.

ABSOLUTE MAXIMUM RATINGS (TA = 25 °C, unless otherwise specified)

Parameter		Symbol	Ratings	Unit
Diode	Forward Current	lF	30	mA
	Reverse Voltage	VR	5	V
	Power Dissipation	PD	60	mW
Detector	Supply Voltage	Vcc	7	V
	Output Voltage	Vo	7	V
	Output Current	lo	50	mA
	Enable Voltage	VE	5.5	V
	Power Dissipation	Pc	85	mW
Isolation Voltage ¹		BV	5 000	Vr.m.s.
Operating Ambient Temperature		TA	-40 to +85	°C
Storage Temperature		T _{stg}	-55 to +125	°C

^{*1} AC voltage for 1 minute at $T_A = 25$ °C, RH = 60 % between input and output.

RECOMMENDED OPERATING CONDITIONS

Parameter	Symbol	MIN.	TYP.	MAX.	Unit
High Level Input Current	lғн	7	10	15	mA
Low Level Input Current	IFL	0		250	μΑ
High Level Enable Voltage	VEH	2		Vcc	٧
Low Level Enable Voltage	VEL	0		0.8	٧
Supply Voltage	Vcc	4.5	5.0	5.5	٧
TTL (loads)	N			8	
Operating Ambient Temperature	TA	0	25	70	°C

*



★ TRUTH TABLE

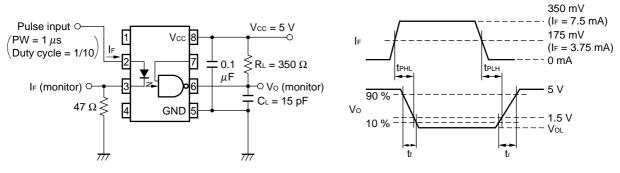
LED	Enable	Output
Н	Н	L
L	Н	Н
Н	L	Н
L	L	Н

ELECTRICAL CHARACTERISTICS (T_A = -40 to +85 °C, unless otherwise specified)

Parameter		Symbol	Conditions	MIN.	TYP.⁴¹	MAX.	Unit
Diode	Forward Voltage	VF	IF = 10 mA, T _A = 25 °C	1.4	1.65	1.9	V
	Reverse Current	IR	VR = 5 V, TA = 25 °C			10	μΑ
	Terminal Capacitance	Ct	V = 0 V, f = 1 MHz, T _A = 25 °C		60		pF
Detector	High Level Output Current	Іон	$V_{CC} = V_{O} = 5.5 \text{ V}, \text{ IF} = 250 \ \mu\text{A}, \ V_{E} = 2 \text{ V}$		2	250	μΑ
	Low Level Output Voltage	Vol	$V_{CC} = 5.5 \text{ V}, \text{ IF} = 5 \text{ mA}, \text{ VE} = 2 \text{ V}, \\ \text{Io} = 13 \text{ mA}$		0.2	0.6	V
	High Level Supply Current	Іссн	Vcc = 5.5 V, VE = 0.5 V, IF = 0 mA	5	7	10	mA
	Low Level Supply Current	Iccl	Vcc = 5.5 V, VE = 2 V, IF = 10 mA	10	13	18	mA
	High Level Enable Current	Ієн	Vcc = 5.5 V, VEH = 2 V	-0.7	-1	-1.5	mA
	Low Level Enable Current	lel	Vcc = 5.5 V, VEL = 0.5 V	-1	-1.4	-2	mA
Coupled	Threshold Input Current $(H \rightarrow L)$	IFHL	$\begin{aligned} &\text{Vcc} = 5 \text{ V, V}_{\text{E}} = 2 \text{ V, Vo} = 0.8 \text{ V,} \\ &\text{RL} = 350 \Omega \end{aligned}$	0.5	2.5	5	mA
	Isolation Resistance	Rı-o	V _{I-O} = 1 kV _{DC} , RH = 40 to 60 %, T _A = 25 °C	1011			Ω
	Isolation Capacitance	C _{I-O}	V = 0 V, f = 1 MHz, T _A = 25 °C		0.6		pF
	Propagation Delay Time $(H \rightarrow L)^{^{*2}}$	t PHL	$\label{eq:Vcc} \begin{array}{l} \mbox{Vcc} = 5 \mbox{ V, I}_F = 7.5 \mbox{ mA, RL} = 350 \ \Omega, \\ \mbox{C}_L = 15 \mbox{ pF, T}_A = 25 \mbox{ °C} \end{array}$		50	75	ns
	Propagation Delay Time $(L \rightarrow H)^{^{*2}}$	tрLН			50	75	ns
	Rise Time ^{'2}	tr			20		ns
	Fall Time ^{'2}	tf			10		ns
	Enable Propagation Delay Time $(H \rightarrow L)^{"3}$	tehl	$V_{\text{CC}} = 5 \text{ V, I}_{\text{F}} = 7.5 \text{ mA, V}_{\text{EH}} = 3 \text{ V,} \\ V_{\text{EL}} = 0.5 \text{ V, R}_{\text{L}} = 350 \ \Omega, \ C_{\text{L}} = 15 \text{ pF,} \\$		10		ns
	Enable Propagation Delay Time $(L \rightarrow H)^3$	telh	T _A = 25 °C		25		ns

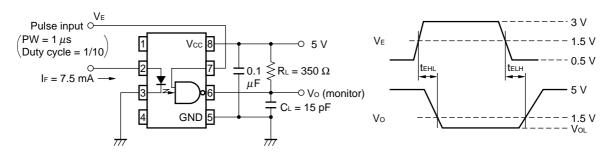
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- ★ *1 Typical values at T_A = 25 °C
 - *2 Test circuit for propagation delay time



C_L includes probe and stray wiring capacitance.

*3 Test circuit for enable propagation delay time



 $\ensuremath{\text{C}_{\text{L}}}$ includes probe and stray wiring capacitance.

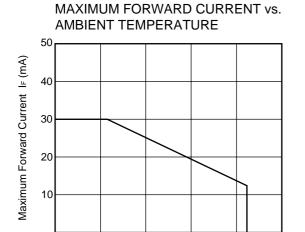
★ USAGE CAUTIONS

- 1. This product is weak for static electricity by designed with high-speed integrated circuit so protect against static electricity when handling.
- 2. By-pass capacitor of more than 0.1 μ F is used between Vcc and GND near device. Also, ensure that the distance between the leads of the photocoupler and capacitor is no more than 10 mm.

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★ TYPICAL CHARACTERISTICS (T_A = 25 °C, unless otherwise specified)

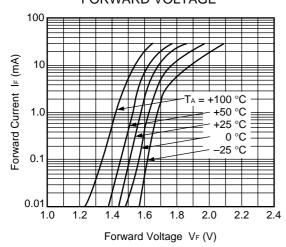
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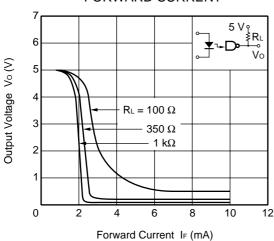
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FORWARD CURRENT vs. FORWARD VOLTAGE

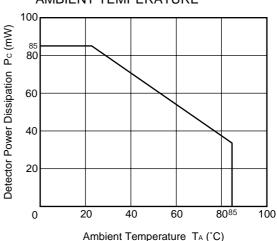
Ambient Temperature TA (°C)



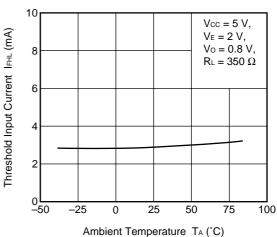
OUTPUT VOLTAGE vs. FORWARD CURRENT



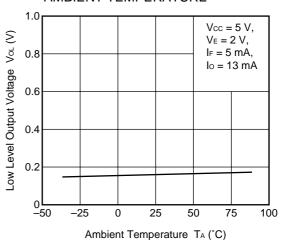
DETECTOR POWER DISSIPATION vs. AMBIENT TEMPERATURE



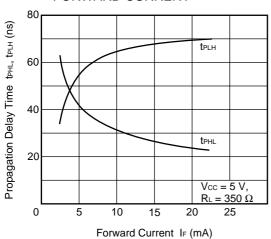
THRESHOLD INPUT CURRENT vs. AMBIENT TEMPERATURE



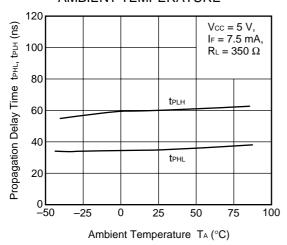
LOW LEVEL OUTPUT VOLTAGE vs. AMBIENT TEMPERATURE



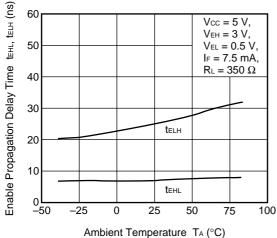
PROPAGATION DELAY TIME vs. FORWARD CURRENT



PROPAGATION DELAY TIME vs. AMBIENT TEMPERATURE

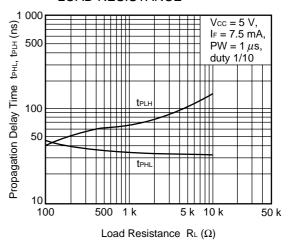


ENABLE PROPAGATION DELAY TIME vs. AMBIENT TEMPERATURE

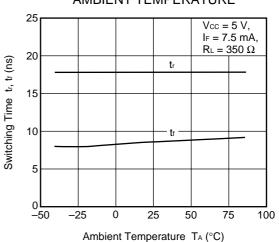


Remark The graphs indicate nominal characteristics.

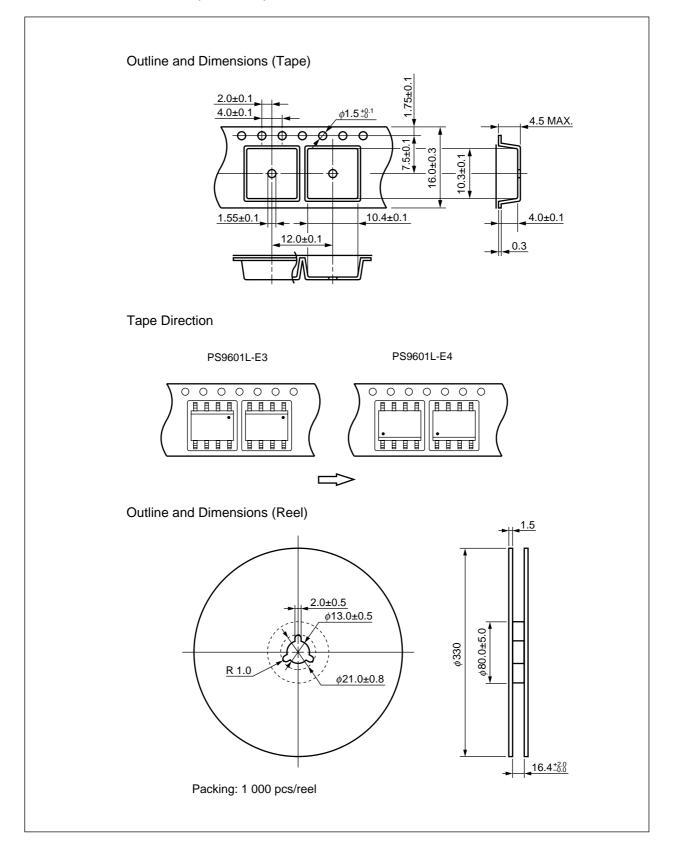
PROPAGATION DELAY TIME vs. LOAD RESISTANCE



SWITCHING TIME vs. AMBIENT TEMPERATURE



★ TAPING SPECIFICATIONS (UNIT: mm)



★ NOTES ON HANDLING

Recommended soldering conditions

(1) Infrared reflow soldering

Peak reflow temperature
 235 °C or below (package surface temperature)

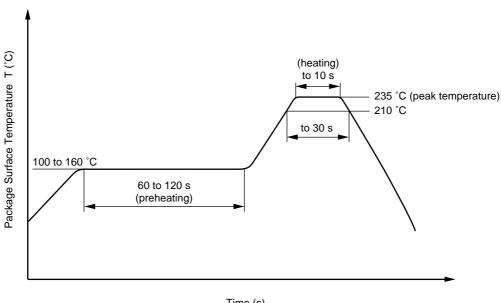
• Time of temperature higher than 210 °C 30 seconds or less

Number of reflows
 Three

• Flux Rosin flux containing small amount of chlorine (The flux with a

maximum chlorine content of 0.2 Wt % is recommended.)

Recommended Temperature Profile of Infrared Reflow



Time (s)

(2) Wave soldering

• Temperature 260 °C or below (molten solder temperature)

• Time 10 seconds or less

• Preheating conditions 100 °C or below (package surface temperature)

• Number of times One (Allowed to be dipped in solder including plastic mold portion.)

• Flux Rosin flux containing small amount of chlorine (The flux with a maximum chlorine

content of 0.2 Wt % is recommended.)

(3) Cautions

Fluxes

Avoid removing the residual flux with freon-based and chlorine-based cleaning solvent.

[MEMO]

SAFETY INFORMATION ON THIS PRODUCT

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GaAs Products

The product contains gallium arsenide, GaAs.

GaAs vapor and powder are hazardous to human health if inhaled or ingested.

- Do not destroy or burn the product.
- Do not cut or cleave off any part of the product.
- · Do not crush or chemically dissolve the product.
- · Do not put the product in the mouth.

Follow related laws and ordinances for disposal. The product should be excluded from general industrial waste or household garbage.

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